

STX112 STX117

Complementary power Darlington transistors

Features

- Good h_{FE} linearity
- High f_T frequency
- Monolithic Darlington configuration with integrated antiparallel collector-emitter diode

Application

■ Linear and switching industrial equipment

Description

The devices are manufactured in planar technology with "base island" layout and monolithic Darlington configuration.

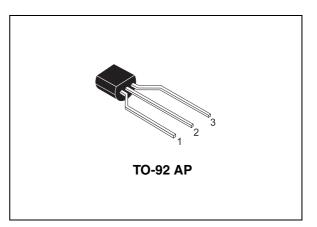


Figure 1. Internal schematic diagram

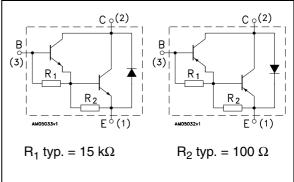


Table 1. Device summary

| Order codes | Marking | Polarity | Package | Packaging |
|-------------|---------|----------|---------|-----------|
| STX112-AP | X112 | NPN | TO92-AP | Ammopack |
| STX117-AP | X117 | PNP | TO92-AP | Ammopack |

Doc ID 6881 Rev 4

1 Absolute maximum ratings

| Table 2. | Absolute | maximum | ratings |
|----------|----------|---------|---------|
| | / | maximam | raingo |

| Symbol | Parameter | Value | Unit |
|------------------|---|------------|------|
| V _{CBO} | Collector-base voltage $(I_E = 0)$ | 100 | V |
| V _{CEO} | Collector-emitter voltage $(I_B = 0)$ | 100 V | |
| V _{EBO} | Emitter-base voltage ($I_C = 0$) | 5 | V |
| ۱ _C | Collector current | 2 | А |
| I _{CM} | Collector peak current | 4 | А |
| I _B | Base current | 0.05 | А |
| P _{TOT} | Total dissipation at T _{amb} = 25 °C | 1.2 | W |
| T _{STG} | Storage temperature | -65 to 150 | °C |
| TJ | Max. operating junction temperature | 150 | °C |

Note: For PNP types voltage and current values are negative.

Table 3.Thermal data

| Symbol | Parameter | Value | Unit |
|-------------------|--|-------|------|
| R _{thJA} | Thermal resistance junction-ambient max. | 104 | °C/W |



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2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

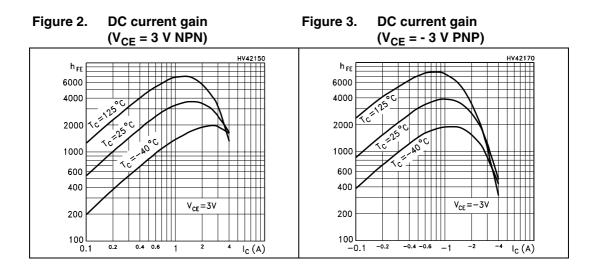
| Table 4. Electrical characteristics | | | | | | | |
|--------------------------------------|--|-------------------------|-----------------------|------|------|------|------|
| Symbol | Parameter | Test con | ditions | Min. | Тур. | Max. | Unit |
| I _{CBO} | Collector cut-off current (I _E = 0) | V _{CB} = 100 V | | | - | 1 | mA |
| I _{CEO} | Collector cut-off current $(I_B = 0)$ | V _{CE} = 50 V | | | - | 2 | mA |
| I _{EBO} | Emitter cut-off current (I _C = 0) | V _{EB} = 5 V | | | - | 2 | mA |
| V _{CEO(sus)} ⁽¹⁾ | Collector-emitter sustaining voltage (I _B = 0) | I _C = 30 mA | | 100 | - | | V |
| V _{CE(sat)} ⁽¹⁾ | Collector-emitter saturation voltage | I _C = 2 A | I _B = 8 mA | | - | 2.5 | V |
| V _{BE(on)} | Base-emitter on voltage | I _C = 2 A | $V_{CE} = 4 V$ | | - | 2.8 | ۷ |
| h _{FE} ⁽¹⁾ | DC current gain | I _C = 1 A | $V_{CE} = 4 V$ | 1000 | - | | |
| | | I _C = 2 A | $V_{CE} = 4 V$ | 500 | - | | |

 Table 4.
 Electrical characteristics

1. Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %

Note: For PNP types voltage and current values are negative.

2.1 Typical characteristic (curves)



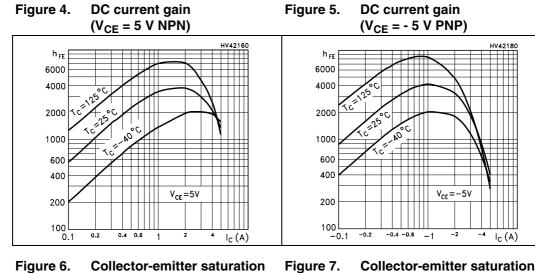
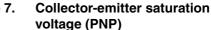
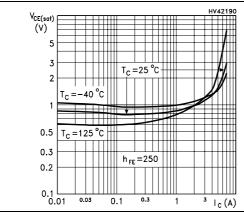


Figure 6. Collector-emitter saturation voltage (NPN)





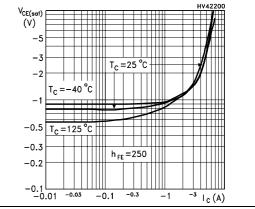


Figure 8. Base-emitter saturation voltage (NPN)

:-40 °C

=25 °C

=125

0.2

0.4 0.6

V_{BE(sat)}

(V)

2

Tr

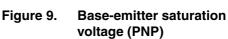
1.75

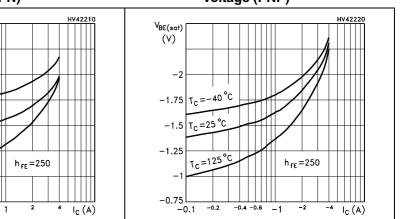
1.5

1.25

0.75

0.1







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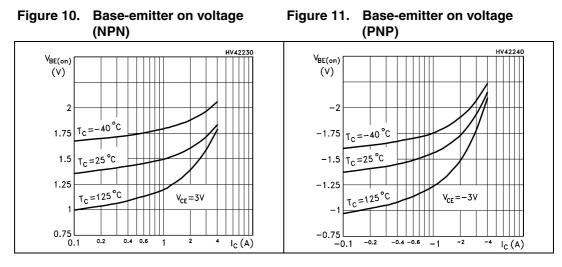


Figure 12. Resistive load switching time Figure 13. Resistive load switching time (NPN, on) (PNP, on)

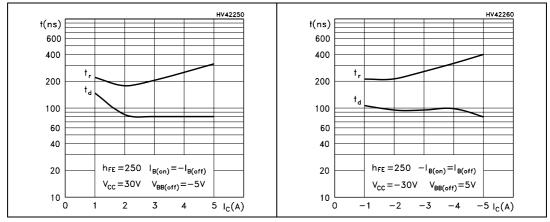
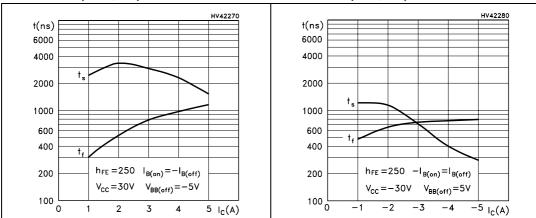


Figure 14. Resistive load switching time Figure 15. Resistive load switching time (NPN, off) (PNP, off)



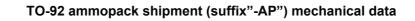
3 Package mechanical data

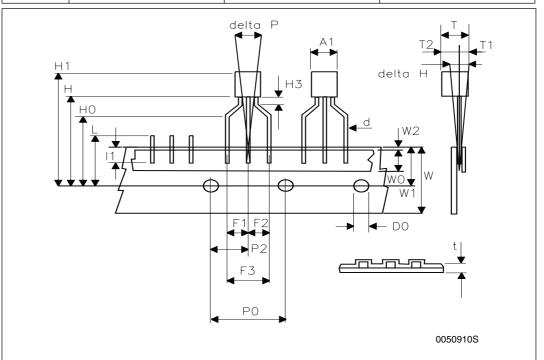
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| Dim. | | mm. | |
|---------|-------|-------|-------|
| | Min. | Тур. | Max. |
| A1 | | | 4.80 |
| Т | | | 3.80 |
| T1 | | | 1.60 |
| T2 | | | 2.30 |
| d | | | 0.48 |
| P0 | 12.50 | 12.70 | 12.90 |
| P2 | 5.65 | 6.35 | 7.05 |
| F1,F2 | 2.44 | 2.54 | 2.94 |
| F3 | 4.98 | 5.08 | 5.48 |
| delta H | -2.00 | | 2.00 |
| W | 17.50 | 18.00 | 19.00 |
| W0 | 5.70 | 6.00 | 6.30 |
| W1 | 8.50 | 9.00 | 9.25 |
| W2 | | | 0.50 |
| Н | 18.50 | | 20.50 |
| H3 | 0.5 | 1 | 1.5 |
| H0 | 15.50 | 16.00 | 16.50 |
| H1 | | | 25.00 |
| D0 | 3.80 | 4.00 | 4.20 |
| t | | | 0.90 |
| L | | | 11.00 |
| 11 | 3.00 | | |
| delta P | -1.00 | | 1.00 |





4 Revision history

Table 5.Document revision history

| Date | Revision | Changes |
|-------------|----------|----------------------------------|
| 21-Jan-2008 | 3 | |
| 07-Apr-2010 | 4 | Updated package mechanical data. |



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